

MR750 SERIES

MR754 and MR760 are Preferred Devices

High Current Lead Mounted Rectifiers

- Current Capacity Comparable to Chassis Mounted Rectifiers
- Very High Surge Capacity
- Insulated Case

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 2.5 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Lead is Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Cathode Polarity Band
- Shipped 1000 units per plastic bag. Available Tape and Reeled, 800 units per reel by adding a "RL" suffix to the part number
- Marking: MR750 — R750
MR751 — R751
MR752 — R752
MR754 — R754
MR756 — R756
MR758 — R758
MR760 — R760

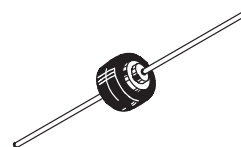


ON Semiconductor

Formerly a Division of Motorola

<http://onsemi.com>

**HIGH CURRENT
LEAD MOUNTED
SILICON RECTIFIERS
50 – 1000 VOLTS
DIFFUSED JUNCTION**



**AXIAL LEAD
CASE 194
STYLE 1**

ORDERING INFORMATION

Device	Package	Shipping
MR750RL	Axial Lead	800/Tape & Reel
MR751RL	Axial Lead	800/Tape & Reel
MR752RL	Axial Lead	800/Tape & Reel
MR754RL	Axial Lead	800/Tape & Reel
MR756RL	Axial Lead	800/Tape & Reel
MR758RL	Axial Lead	800/Tape & Reel
MR760RL	Axial Lead	800/Tape & Reel

Preferred devices are recommended choices for future use and best overall value.

MR750 SERIES

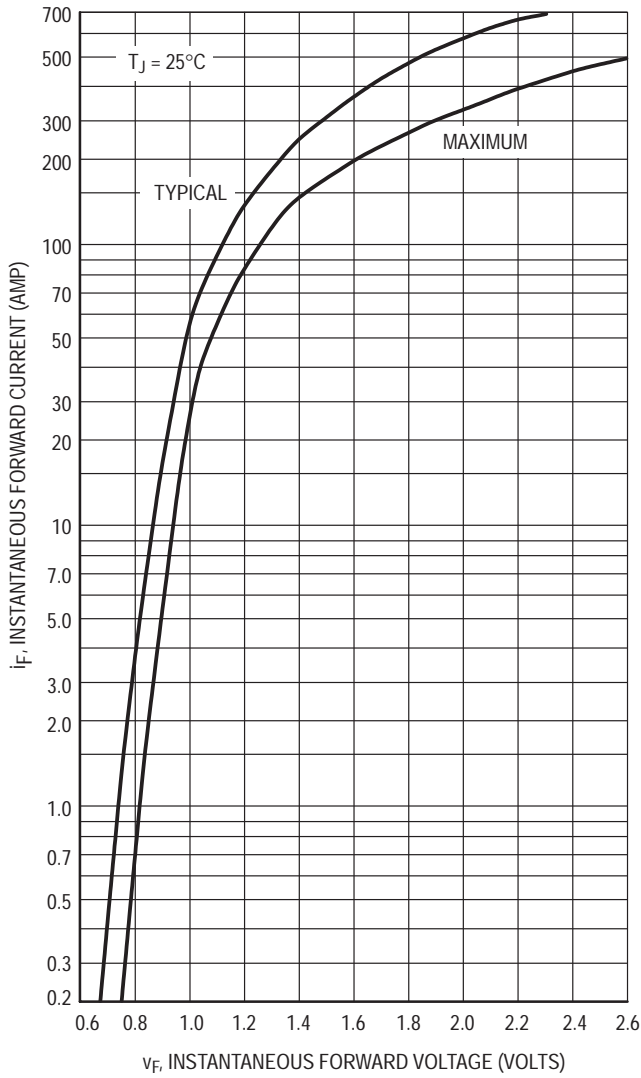


Figure 1. Forward Voltage

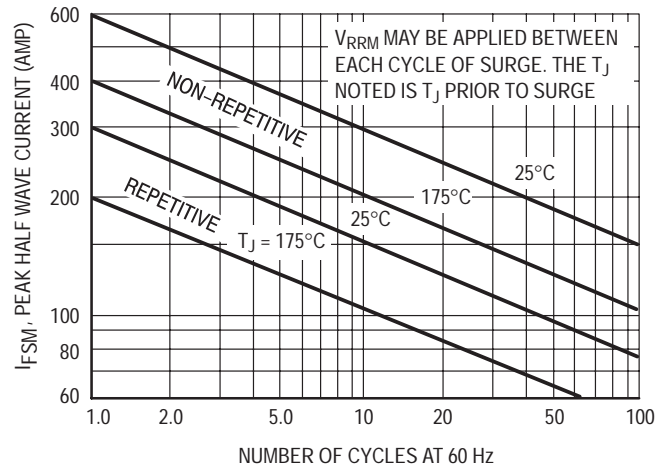


Figure 2. Maximum Surge Capability

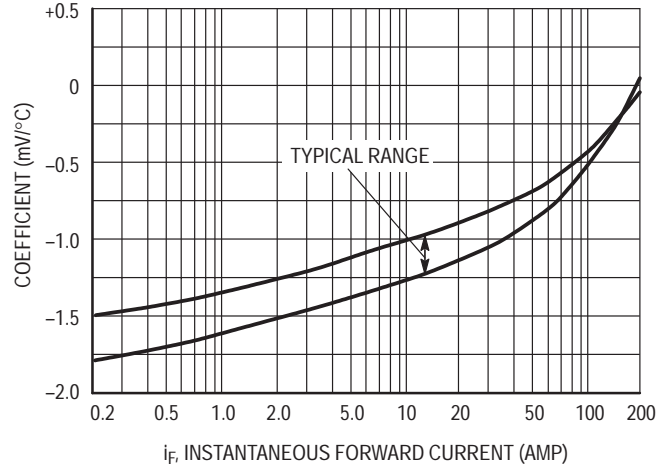


Figure 3. Forward Voltage Temperature Coefficient

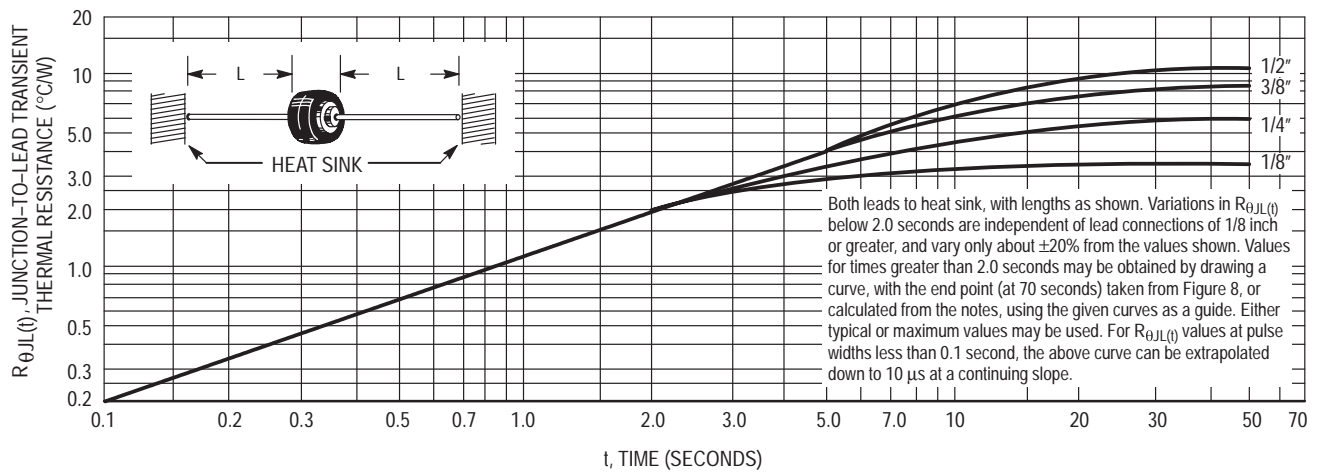


Figure 4. Typical Transient Thermal Resistance

MR750 SERIES

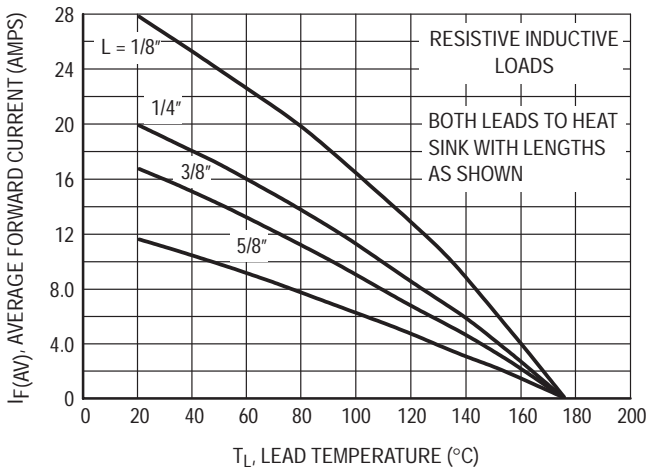


Figure 5. Maximum Current Ratings

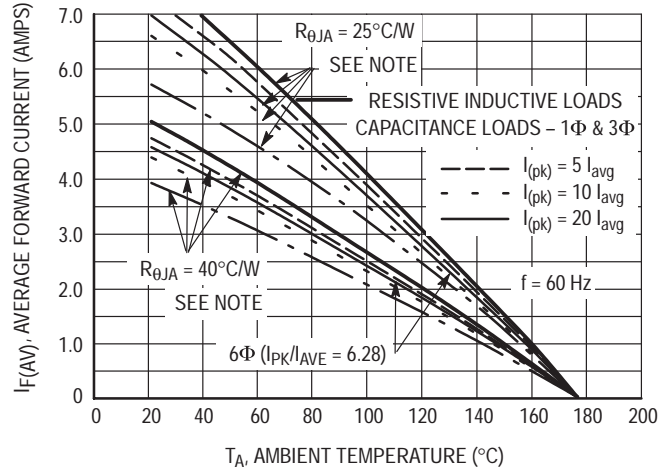


Figure 6. Maximum Current Ratings

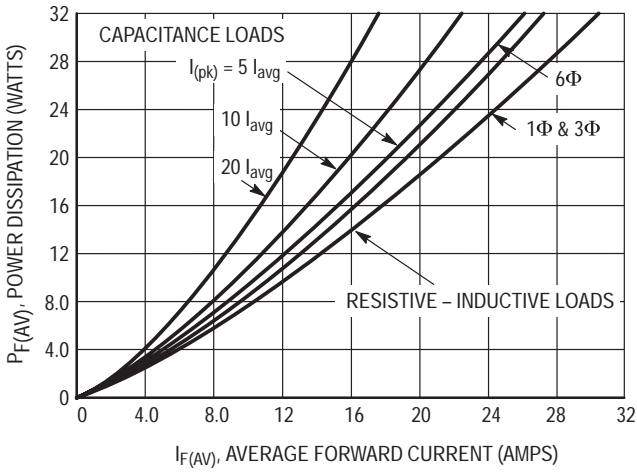


Figure 7. Power Dissipation

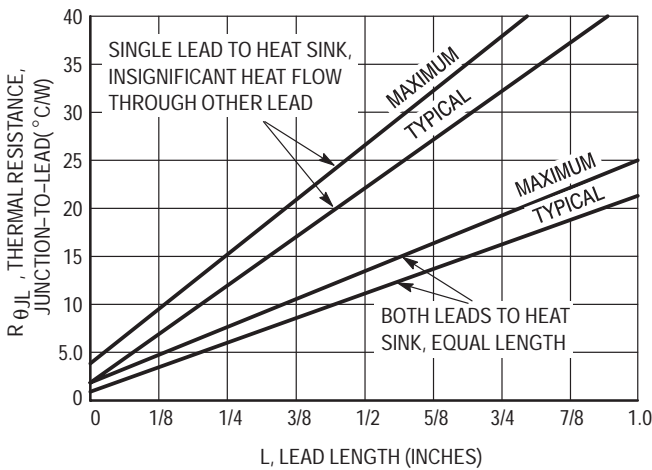
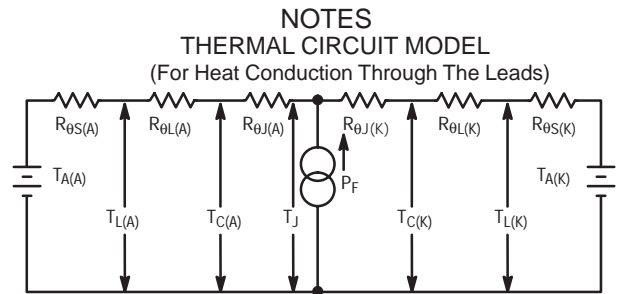


Figure 8. Steady State Thermal Resistance



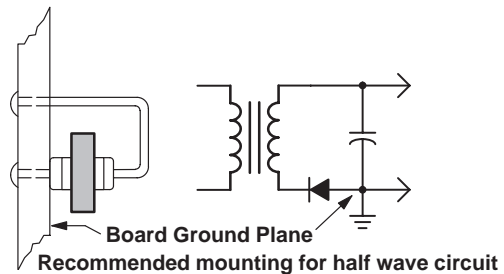
Use of the above model permits junction to lead thermal resistance for any mounting configuration to be found. Lowest values occur when one side of the rectifier is brought as close as possible to the heat sink as shown below. Terms in the model signify:

- T_A = Ambient Temperature
 - T_L = Lead Temperature
 - $R_{\theta S}$ = Thermal Resistance, Heat Sink to Ambient
 - $R_{\theta L}$ = Thermal Resistance, Lead to Heat Sink
 - $R_{\theta J}$ = Thermal Resistance, Junction to Case
 - P_F = Power Dissipation
 - T_C = Case Temperature
 - T_J = Junction Temperature
- (Subscripts A and K refer to anode and cathode sides, respectively)

Values for thermal resistance components are:
 $R_{\theta L} = 40^\circ\text{C/W/in. Typically and } 44^\circ\text{C/W/in Maximum.}$
 $R_{\theta J} = 2^\circ\text{C/W typically and } 4^\circ\text{C/W Maximum.}$

Since $R_{\theta J}$ is so low, measurements of the case temperature, T_C , will be approximately equal to junction temperature in practical lead mounted applications. When used as a 60 Hz rectifier the slow thermal response holds $T_{J(pk)}$ close to $T_{J(ave)}$. Therefore maximum lead temperature may be found from: $T_L = 175^\circ - R_{\theta JL} P_F$. P_F may be found from Figure 7.

The recommended method of mounting to a P.C. board is shown on the sketch, where $R_{\theta JA}$ is approximately 25°C/W for a $1-1/2" \times 1-1/2"$ copper surface area. Values of 40°C/W are typical for mounting to terminal strips or P.C. boards where available surface area is small.



MR750 SERIES

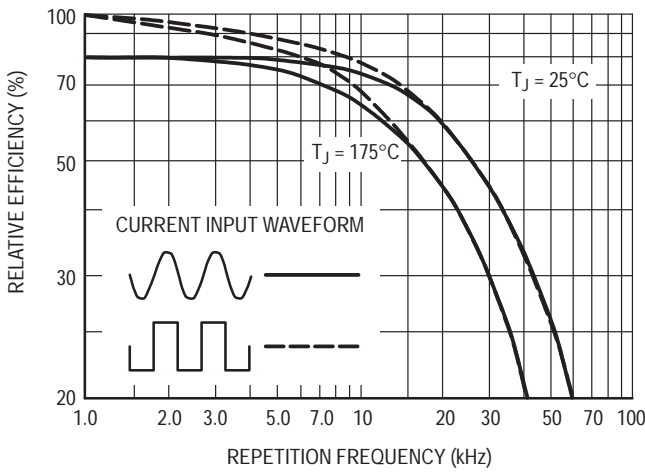


Figure 9. Rectification Efficiency

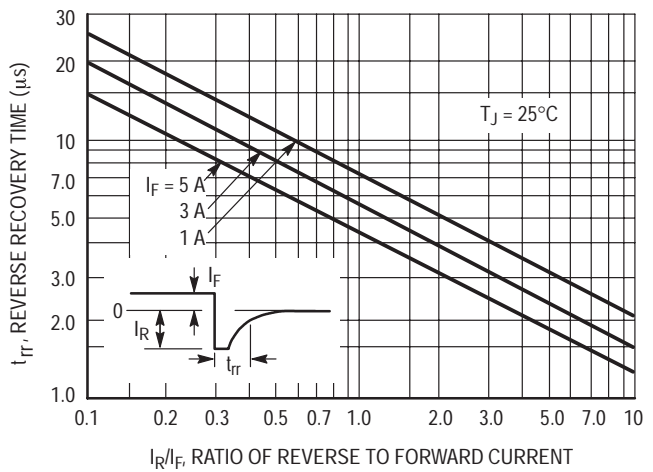


Figure 10. Reverse Recovery Time

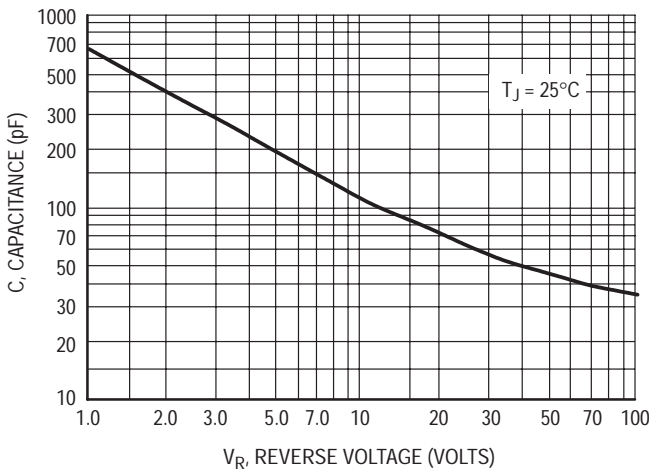


Figure 11. Junction Capacitance

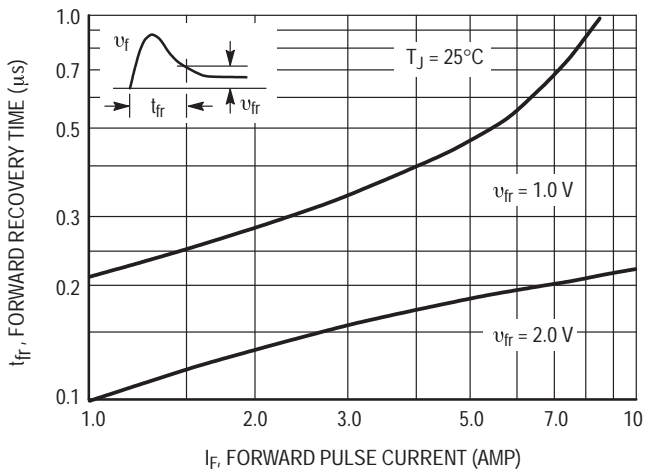


Figure 12. Forward Recovery Time

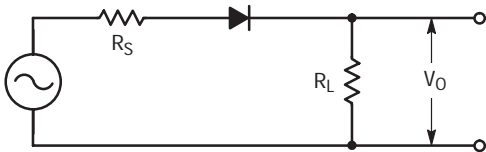


Figure 13. Single-Phase Half-Wave Rectifier Circuit

The rectification efficiency factor σ shown in Figure 9 was calculated using the formula:

$$\sigma = \frac{P_{(dc)}}{P_{(rms)}} = \frac{\frac{V_{2O(dc)}}{R_L}}{\frac{V_{2O(rms)}}{R_L}} \cdot 100\% = \frac{V_{2O(dc)}}{V_{2O(ac)} + V_{2O(dc)}} \cdot 100\% \quad (1)$$

For a sine wave input $V_m \sin(\omega t)$ to the diode, assumed lossless, the maximum theoretical efficiency factor becomes:

$$\sigma_{(sine)} = \frac{\frac{V_{2m}}{\pi^2 R_L}}{\frac{V_{2m}}{4R_L}} \cdot 100\% = \frac{4}{\pi^2} \cdot 100\% = 40.6\% \quad (2)$$

For a square wave input of amplitude V_m , the efficiency factor becomes:

$$\sigma_{(square)} = \frac{\frac{V_{2m}}{2R_L}}{\frac{V_{2m}}{R_L}} \cdot 100\% = 50\% \quad (3)$$

(A full wave circuit has twice these efficiencies)

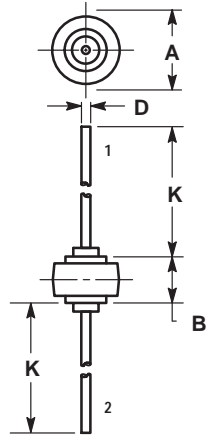
As the frequency of the input signal is increased, the reverse recovery time of the diode (Figure 10) becomes significant, resulting in an increasing ac voltage component across R_L which is opposite in polarity to the forward current, thereby reducing the value of the efficiency factor σ , as shown on Figure 9.

It should be emphasized that Figure 9 shows waveform efficiency only; it does not provide a measure of diode losses. Data was obtained by measuring the ac component of V_o with a true rms ac voltmeter and the dc component with a dc voltmeter. The data was used in Equation 1 to obtain points for Figure 9.

MR750 SERIES

PACKAGE DIMENSIONS

AXIAL LEAD
CASE 194-04
ISSUE F




NOTES:
1. CATHODE SYMBOL ON PACKAGE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.43	8.69	0.332	0.342
B	5.94	6.25	0.234	0.246
D	1.27	1.35	0.050	0.053
K	25.15	25.65	0.990	1.010

STYLE 1:
PIN 1. CATHODE
2. ANODE

Notes

MR750 SERIES

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

PUBLICATION ORDERING INFORMATION

North America Literature Fulfillment:

Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: ONlit@hibbertco.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

EUROPE: LDC for ON Semiconductor – European Support

German Phone: (+1) 303-308-7140 (M-F 2:30pm to 5:00pm Munich Time)
Email: ONlit-german@hibbertco.com
French Phone: (+1) 303-308-7141 (M-F 2:30pm to 5:00pm Toulouse Time)
Email: ONlit-french@hibbertco.com
English Phone: (+1) 303-308-7142 (M-F 1:30pm to 5:00pm UK Time)
Email: ONlit@hibbertco.com

ASIA/PACIFIC: LDC for ON Semiconductor – Asia Support

Phone: 303-675-2121 (Tue-Fri 9:00am to 1:00pm, Hong Kong Time)
Toll Free from Hong Kong 800-4422-3781
Email: ONlit-asia@hibbertco.com

JAPAN: ON Semiconductor, Japan Customer Focus Center

4-32-1 Nishi-Gotanda, Shinagawa-ku, Tokyo, Japan 141-8549
Phone: 81-3-5487-8345
Email: r14153@onsemi.com

Fax Response Line: 303-675-2167
800-344-3810 Toll Free USA/Canada

ON Semiconductor Website: <http://onsemi.com>

For additional information, please contact your local Sales Representative.